

DC CHARACTERISTICS (CONTINUED)

Electrical Specifications: Unless otherwise indicated, all limits are specified for $V_{DD} = 1V$ to $5.5V$, $R_{PU} = 100\text{ k}\Omega$ (only **MCP111**), $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$.

Parameters		Sym	Min	Typ	Max	Units	Conditions
Threshold Hysteresis (min. = 1%, max = 6%)	MCP1XX-195	V_{HYS}	0.019	—	0.114	V	$T_A = +25^\circ\text{C}$
	MCP1XX-240		0.023	—	0.139	V	
	MCP1XX-270		0.026	—	0.158	V	
	MCP1XX-290		0.029	—	0.174	V	
	MCP1XX-300		0.029	—	0.176	V	
	MCP1XX-315		0.031	—	0.185	V	
	MCP1XX-450		0.044	—	0.263	V	
	MCP1XX-475		0.046	—	0.278	V	
V_{OUT} Low-level Output Voltage		V_{OL}	—	—	0.4	V	$I_{OL} = 500\text{ }\mu\text{A}$, $V_{DD} = V_{TRIP(MIN)}$
V_{OUT} High-level Output Voltage		V_{OH}	$V_{DD} - 0.6$	—	—	V	$I_{OH} = 1\text{ mA}$, For only MCP112 (push-pull output)
Open-drain High Voltage on Output		V_{ODH}	—	—	13.5 ⁽³⁾	V	MCP111 only, $V_{DD} = 3.0V$, Time voltage > $5.5V$ applied $\leq 100s$, current into pin limited to 2 mA , $+25^\circ\text{C}$ operation recommended Note 3, Note 4
Open-drain Output Leakage Current (MCP111 only)		I_{OD}	—	0.1	—	μA	

Note 1: Trip point is $\pm 1.5\%$ from typical value.

2: Trip point is $\pm 2.5\%$ from typical value.

3: This specification allows this device to be used in PICmicro[®] microcontroller applications that require the In-Circuit Serial Programming[™] (ICSP[™]) feature (see device-specific programming specifications for voltage requirements). This specification DOES NOT allow a continuous high voltage to be present on the open-drain output pin (V_{OUT}). The total time that the V_{OUT} pin can be above the maximum device operational voltage ($5.5V$) is 100 sec . Current into the V_{OUT} pin should be limited to 2 mA . It is recommended that the device operational temperature be maintained between 0°C to 70°C ($+25^\circ\text{C}$ preferred). For additional information, please refer to Figure 2-28.

4: This parameter is established by characterization and is not 100% tested.